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## INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)

3836.001

Application Number

10/554,136

Applicant(s)

Hiroshi KAWAZOE

Filing Date

May 12, 2006

Group Art Unit

2811

## U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

## U.S. PATENT APPLICATION PUBLICATIONS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

## FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

## OTHER DOCUMENTS

(Including Author, Title, Date, Pertinent Pages, Etc.)

/H.H./		PARK et al., "p-type ZnSe by nitrogen atom beam doping during molecular beam epitaxial growth" Applied Physics Letters, Vol. 57, No. 20, 12 November 1990, pp. 2127- 2129

EXAMINER

/Hsin Yi Hsieh/

DATE CONSIDERED

03/28/2009

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.